Low-Voltage CMOS Quad Buffer

With 5 V-Tolerant Inputs and Outputs (3-State, Non-Inverting)

The MC74LCX125 is a high performance, non–inverting quad buffer operating from a 2.3 to 3.6 V supply. High impedance TTL compatible inputs significantly reduce current loading to input drivers while TTL compatible outputs offer improved switching noise performance. A V_I specification of 5.5 V allows MC74LCX125 inputs to be safely driven from 5.0 V devices. The MC74LCX125 is suitable for memory address driving and all TTL level bus oriented transceiver applications.

Current drive capability is 24 mA at the outputs. The Output Enable $(\overline{OE}n)$ inputs, when HIGH, disable the outputs by placing them in a HIGH Z condition.

Features

- Designed for 2.3 to 3.6 V V_{CC} Operation
- 5.0 V Tolerant Interface Capability With 5.0 V TTL Logic
- Supports Live Insertion and Withdrawal
- I_{OFF} Specification Guarantees High Impedance When $V_{CC} = 0 \text{ V}$
- LVTTL Compatible
- LVCMOS Compatible
- 24 mA Balanced Output Sink and Source Capability
- Near Zero Static Supply Current in all Three Logic States (10 μA)
 Substantially Reduces System Power Requirements
- Latchup Performance Exceeds 500 mA
- ESD Performance: Human Body Model >2000 V
- Machine Model >200 V
 These Devices are Pb–Free and are RoHS Compliant



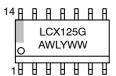
ON Semiconductor®

http://onsemi.com

MARKING DIAGRAMS



SOIC-14 D SUFFIX CASE 751A





TSSOP-14 DT SUFFIX CASE 948G



A = Assembly Location

L, WL = Wafer Lot Y, YY = Year W, WW = Work Week G or = Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

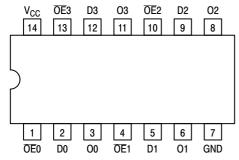


Figure 1. Pinout: 14-Lead (Top View)

Figure 2. Logic Diagram

PIN NAMES

| Pins | Function |
|-----------------|----------------------|
| OE n | Output Enable Inputs |
| Dn | Data Inputs |
| On | 3-State Outputs |

TRUTH TABLE

| INP | INPUTS | | |
|-----------------|--------|----|--|
| OE n | Dn | On | |
| L | L | L | |
| L | Н | Н | |
| Н | Х | Z | |

H = High Voltage Level
L = Low Voltage Level
Z = High Impedance State

 $X = High \ or \ Low \ Voltage \ Level \ and \ Transitions \ Are \ Acceptable; for \ I_{CC} \ reasons, \ DO \ NOT \ FLOAT \ Inputs$

MAXIMUM RATINGS

| Symbol | Parameter | Value | Condition | Units |
|------------------|----------------------------------|-----------------------------------|---------------------------------------|-------|
| V _{CC} | DC Supply Voltage | −0.5 to +7.0 | | V |
| VI | DC Input Voltage | $-0.5 \le V_{I} \le +7.0$ | | V |
| V _O | DC Output Voltage | $-0.5 \le V_{O} \le +7.0$ | Output in 3-State | V |
| | | $-0.5 \le V_{O} \le V_{CC} + 0.5$ | Output in HIGH or LOW State. (Note 1) | V |
| l _{IK} | DC Input Diode Current | -50 | V _I < GND | mA |
| I _{OK} | DC Output Diode Current | -50 | V _O < GND | mA |
| | | +50 | V _O > V _{CC} | mA |
| I _O | DC Output Source/Sink Current | ±50 | | mA |
| Icc | DC Supply Current Per Supply Pin | ±100 | | mA |
| I _{GND} | DC Ground Current Per Ground Pin | ±100 | | mA |
| T _{STG} | Storage Temperature Range | -65 to +150 | | °C |

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

1. IO absolute maximum rating must be observed.

RECOMMENDED OPERATING CONDITIONS

| Symbol | Parameter | Min | Тур | Max | Units |
|---------------------|--|------------|----------------------|---------------------|-------|
| V _{CC} | Supply Voltage Operating Data Retention Only | 2.0 1.5 | 2.5, 3.3 2.5, 3.3 | 3.6 3.6 | V |
| VI | Input Voltage | 0 | | 5.5 | V |
| V _O | Output Voltage HIGH or LOW State 3-State | 0 | | V _{CC} 5.5 | V |
| I _{OH} | HIGH Level Output Current V _{CC} = 3.0 V - 3.6 V V _{CC} = 2.7 V - 3.0 V V _{CC} = 2.3 V - 2.7 V | | | -24 -12 -8 | mA |
| I _{OL} | LOW Level Output Current V _{CC} = 3.0 V - 3.6 V V _{CC} = 2.7 V - 3.0 V V _{CC} = 2.3 V - 2.7 V | | | +24 +12 +8 | mA |
| T _A | Operating Free-Air Temperature | -40 | | +85 | °C |
| $\Delta t/\Delta V$ | Input Transition Rise or Fall Rate, V_{IN} from 0.8 V to 2.0 V, V_{CC} = 3.0 V | 0 | | 10 | ns/V |

DC ELECTRICAL CHARACTERISTICS

| | | | T _A = −40°C | to +85°C | |
|-----------------|---------------------------------------|---|------------------------|----------|-------|
| Symbol | Characteristic | Condition | Min | Max | Units |
| V _{IH} | HIGH Level Input Voltage (Note 2) | 2.3 V ≤ V _{CC} ≤ 2.7 V | 1.7 | | V |
| | | 2.7 V ≤ V _{CC} ≤ 3.6 V | 2.0 | | |
| V _{IL} | LOW Level Input Voltage (Note 2) | 2.3 V ≤ V _{CC} ≤ 2.7 V | | 0.7 | V |
| | | 2.7 V ≤ V _{CC} ≤ 3.6 V | | 0.8 | |
| V _{OH} | HIGH Level Output Voltage | $2.3 \text{ V} \le \text{V}_{CC} \le 3.6 \text{ V}; \text{I}_{OL} = 100 \mu\text{A}$ | V _{CC} - 0.2 | | V |
| | | V _{CC} = 2.3 V; I _{OH} = -8 mA | 1.8 | | |
| | | V _{CC} = 2.7 V; I _{OH} = -12 mA | 2.2 | | |
| | | V _{CC} = 3.0 V; I _{OH} = -18 mA | 2.4 | | |
| | | V _{CC} = 3.0 V; I _{OH} = -24 mA | 2.2 | | |
| V _{OL} | LOW Level Output Voltage | $2.3 \text{ V} \le \text{V}_{CC} \le 3.6 \text{ V}; \text{I}_{OL} = 100 \mu\text{A}$ | | 0.2 | V |
| | | V _{CC} = 2.3 V; I _{OL} = 8 mA | | 0.6 | |
| | | V _{CC} = 2.7 V; I _{OL} = 12 mA | | 0.4 | |
| | | V _{CC} = 3.0 V; I _{OL} = 16 mA | | 0.4 | |
| | | V _{CC} = 3.0 V; I _{OL} = 24 mA | | 0.55 | |
| II | Input Leakage Current | $2.3 \text{ V} \le \text{V}_{CC} \le 3.6 \text{ V}; 0 \text{ V} \le \text{V}_{I} \le 5.5 \text{ V}$ | | ±5 | μΑ |
| I _{CC} | Quiescent Supply Current | $2.3 \le V_{CC} \le 3.6 \text{ V}; V_I = \text{GND or } V_{CC}$ | | 10 | μΑ |
| | | $2.3 \le V_{CC} \le 3.6 \text{ V}; 3.6 \le V_I \text{ or } V_O \le 5.5 \text{ V}$ | | ±10 | |
| ΔI_{CC} | Increase in I _{CC} per Input | $2.3 \le V_{CC} \le 3.6 \text{ V}; V_{IH} = V_{CC} - 0.6 \text{ V}$ | | 500 | μА |

^{2.} These values of V_I are used to test DC electrical characteristics only.

AC CHARACTERISTICS t_R = t_F = 2.5 ns; R_L = 500 Ω

| | | | Limits | | | | | | |
|--------------------------------------|--|----------|------------------------------|---------------------------------|---------------------|------------|-----------------------|------------|-------|
| | | | | T _A = -40°C to +85°C | | | | | |
| | | | V_{CC} = 3.3 V \pm 0.3 V | | V _{CC} = | 2.7 V | V _{CC} = 2.5 | V ± 0.2 V | |
| | | | C _L = | 50 pF | C _L = \$ | 50 pF | C _L = 3 | 30 pF | |
| Symbol | Parameter | Waveform | Min | Max | Min | Max | Min | Max | Units |
| t _{PLH} t _{PHL} | Propagation Delay Time Input to Output | 1 | 1.5 1.5 | 6.0 6.0 | 1.5 1.5 | 6.5 6.5 | 1.5 1.5 | 7.2 7.2 | ns |
| t _{PZH} t _{PZL} | Output Enable Time to High and Low Level | 2 | 1.5 1.5 | 7.0 7.0 | 1.5 1.5 | 8.0 8.0 | 1.5 1.5 | 9.1 9.1 | ns |
| t _{PHZ} t _{PLZ} | Output Disable Time From High and Low Level | 2 | 1.5 1.5 | 6.0 6.0 | 1.5 1.5 | 7.0 7.0 | 1.5 1.5 | 7.2 7.2 | ns |
| toshl toslh | Output-to-Output Skew (Note 3) | | | 1.0 1.0 | | | | | ns |

Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device.
 The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}); parameter guaranteed by design.

DYNAMIC SWITCHING CHARACTERISTICS

| | | | T _A = +25°C | | | |
|------------------|--------------------------------------|--|------------------------|--------------|-----|-------|
| Symbol | Characteristic | Condition | Min | Тур | Max | Units |
| V _{OLP} | Dynamic LOW Peak Voltage (Note 4) | $\begin{aligned} &V_{CC} = 3.3 \text{ V, } C_{L} = 50 \text{ pF, } V_{IH} = 3.3 \text{ V, } V_{IL} = 0 \text{ V} \\ &V_{CC} = 2.5 \text{ V, } C_{L} = 30 \text{ pF, } V_{IH} = 2.5 \text{ V, } V_{IL} = 0 \text{ V} \end{aligned}$ | | 0.8 0.6 | | V |
| V _{OLV} | Dynamic LOW Valley Voltage (Note 4) | $\begin{array}{c} V_{CC} = 3.3 \text{ V, } C_L = 50 \text{ pF, } V_{IH} = 3.3 \text{ V, } V_{IL} = 0 \text{ V} \\ V_{CC} = 2.5 \text{ V, } C_L = 30 \text{ pF, } V_{IH} = 2.5 \text{ V, } V_{IL} = 0 \text{ V} \end{array}$ | | -0.8 -0.6 | | V |

^{4.} Number of outputs defined as "n". Measured with "n-1" outputs switching from HIGH-to-LOW or LOW-to-HIGH. The remaining output is measured in the LOW state.

CAPACITIVE CHARACTERISTICS

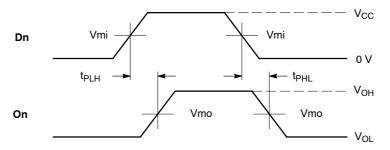
| Symbol | Parameter | Condition | Typical | Units |
|------------------|-------------------------------|--|---------|-------|
| C _{IN} | Input Capacitance | $V_{CC} = 3.3 \text{ V}, V_I = 0 \text{ V or } V_{CC}$ | 7 | pF |
| C _{OUT} | Output Capacitance | V_{CC} = 3.3 V, V_I = 0 V or V_{CC} | 8 | pF |
| C _{PD} | Power Dissipation Capacitance | 10 MHz, V _{CC} = 3.3 V, V _I = 0 V or V _{CC} | 25 | pF |

ORDERING INFORMATION

| Device | Package | Shipping [†] |
|-----------------|----------------------|-----------------------|
| MC74LCX125DG | SOIC-14 (Pb-Free) | 55 Units / Rail |
| MC74LCX125DR2G | SOIC-14 (Pb-Free) | 2500 Tape & Reel |
| MC74LCX125DTG | TSSOP-14* | 96 Units / Rail |
| MC74LCX125DTR2G | TSSOP-14* | 2500 Tape & Reel |

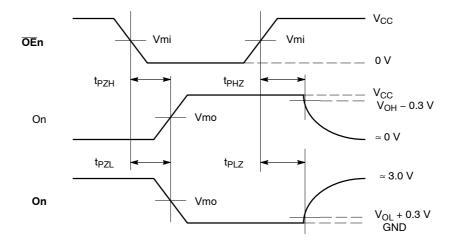
[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

^{*}This package is inherently Pb-Free.



WAVEFORM 1 - PROPAGATION DELAYS

 $t_{R} = t_{F} = 2.5 \text{ ns}, 10\% \text{ to } 90\%; f = 1 \text{ MHz}; t_{W} = 500 \text{ ns}$

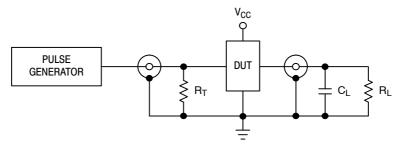


WAVEFORM 2 - OUTPUT ENABLE AND DISABLE TIMES

 $t_R = t_F = 2.5 \text{ ns}, 10\% \text{ to } 90\%; f = 1 \text{ MHz}; t_W = 500 \text{ ns}$

| | V _{CC} | | | | |
|--------|-----------------|-------|--------------------|--|--|
| Symbol | 3.3 V ± 0.3 V | 2.7 V | 2.5 V ± 0.2 V | | |
| Vmi | 1.5 V | 1.5 V | V _{CC} /2 | | |
| Vmo | 1.5 V | 1.5 V | V _{CC} /2 | | |

Figure 3. AC Waveforms



 C_L = $\,$ 50 pF at V_{CC} = $\,$ 3.3 ± 0.3 V or equivalent (includes jig and probe capacitance)

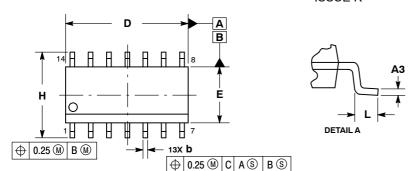
 C_L = 30 pF at V_{CC} = 2.5 ± 0.2 V or equivalent (includes jig and probe capacitance) R_L = R_1 = 500 Ω or equivalent

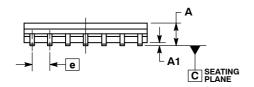
 $R_T = Z_{OUT}$ of pulse generator (typically 50 Ω)

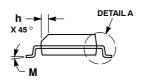
Figure 4. Test Circuit

PACKAGE DIMENSIONS

SOIC-14 NB CASE 751A-03 ISSUE K







- NOTES:

 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.

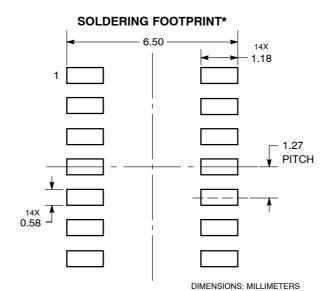
 2. CONTROLLING DIMENSION: MILLIMETERS.

 3. DIMENSION b DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS OF AT MAXIMUM MATERIAL CONDITION.

 4. DIMENSIONS D AND E DO NOT INCLUDE MOLD PROTRUSIONS.

 5. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.

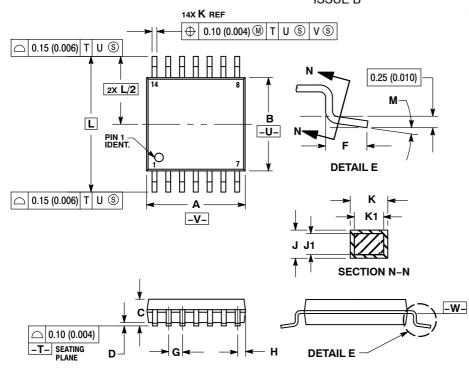
| | MILLIMETERS | | RS INCHES | |
|-----|-------------|----------|-----------|-------|
| DIM | MIN | MAX | MIN | MAX |
| Α | 1.35 | 1.75 | 0.054 | 0.068 |
| A1 | 0.10 | 0.25 | 0.004 | 0.010 |
| А3 | 0.19 | 0.25 | 0.008 | 0.010 |
| b | 0.35 | 0.49 | 0.014 | 0.019 |
| D | 8.55 | 8.75 | 0.337 | 0.344 |
| Ε | 3.80 | 4.00 | 0.150 | 0.157 |
| е | 1.27 | 1.27 BSC | | BSC |
| Н | 5.80 | 6.20 | 0.228 | 0.244 |
| h | 0.25 | 0.50 | 0.010 | 0.019 |
| L | 0.40 | 1.25 | 0.016 | 0.049 |
| М | 0 ° | 7° | 0° | 7° |



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

PACKAGE DIMENSIONS

TSSOP-14 CASE 948G-01 ISSUE B



NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 CONTROLLING DIMENSION: MILLIMETER.
- CONTROLLING DIMENSION: MILLIMETER.
 DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.
- MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.

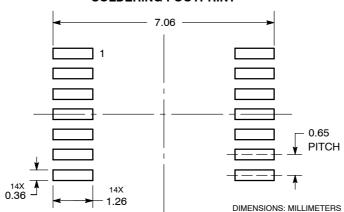
 4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.

 5. DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE
- 5. DIMENSION K DÖES NÖT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION.
- 6. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
- REFERENCE ONLY.

 7. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-.

| | MILLIMETERS | | INCHES | |
|-----|-------------|------|-----------|-------|
| DIM | MIN | MAX | MIN | MAX |
| Α | 4.90 | 5.10 | 0.193 | 0.200 |
| В | 4.30 | 4.50 | 0.169 | 0.177 |
| С | | 1.20 | | 0.047 |
| D | 0.05 | 0.15 | 0.002 | 0.006 |
| F | 0.50 | 0.75 | 0.020 | 0.030 |
| G | 0.65 | BSC | 0.026 BSC | |
| Н | 0.50 | 0.60 | 0.020 | 0.024 |
| J | 0.09 | 0.20 | 0.004 | 0.008 |
| J1 | 0.09 | 0.16 | 0.004 | 0.006 |
| K | 0.19 | 0.30 | 0.007 | 0.012 |
| K1 | 0.19 | 0.25 | 0.007 | 0.010 |
| L | 6.40 BSC | | 0.252 | BSC |
| М | 0 ° | 8 ° | 0 ° | 8 ° |

SOLDERING FOOTPRINT



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